REVISIONS			
LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Boilerplate update, part of 5 year review. ksr	06-11-08	Raymond Monnin

THE ORIGINAL FIRST SHEET OF THIS DRAWING HAS BEEN REPLACED.

REV																				
SHEET																				
REV	A	A	A	A	A	A														
SHEET	15	16	17	18	19	20														

REV STATUS	REV	A	A	A	A	A	A	A	A	A	A	A	A	A	A
OF SHEETS	SHEET	1	2	3	4	5	6	7	8	9	10	11	12	13	14

PMIC N/A

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90-09-17

REVISION LEVEL
A

DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43218-3990
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STANDARD MICROCIRCUIT DRAWING

THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE

AMSC N/A

MICROCIRCUIT, MEMORY, DIGITAL, CMOS, PARALLEL 512 X 9 FIFO , MONOLITHIC SILICON

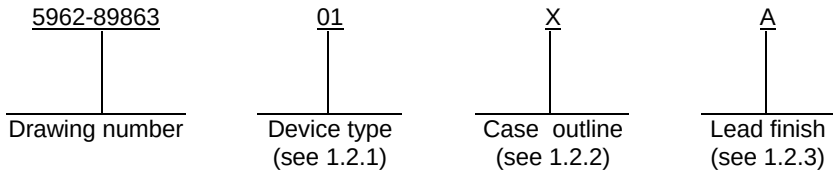
SIZE	CAGE CODE	
A	**67268**	**5962-89863**

SHEET 1 OF 20

1. SCOPE

1.1 Scope. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number 1/	Circuit function	Acess time
01		512 X 9 FIFO	80 ns
02		512 X 9 FIFO	65 ns
03		512 X 9 FIFO	50 ns
04		512 X 9 FIFO	40 ns
05		512 X 9 FIFO	30 ns
06		512 X 9 FIFO	25 ns

1.2.2 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
X	GDIP1-T28 or CDIP2-T28	28	dual-in-line package
Y	CDIP3-T28 or GDIP4-T28	28	dual-in-line package
Z	CQCC1-N32	32	rectangular chip carrier package
U	GDFP2-F28	28	flat package

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

1.3 Absolute maximum ratings.

Supply voltage to ground potential	-0.5 V dc to +7.0 V dc
DC voltage applied to outputs in high Z state	-0.5 V dc to +7.0 V dc
DC input voltage	-0.3 V dc to +7.0 V dc
DC output current	20 mA
Maximum power dissipation 2/	1.0 W
Lead temperature (soldering, 10 seconds)	+260°C
Thermal resistance, junction-to-case (Θ_{JC})	See MIL-STD-1835
Junction temperature (T_J) 3/	+150°C
Storage temperature range	-65°C to +150°C
Temperature under bias	-55°C to +125°C

1.4 Recommended operating conditions.

Supply voltage (V_{CC})	+4.5 V dc to +5.5 V dc
Ground voltage (GND)	0 V dc
Input high voltage (V_{IH})	2.2 V dc minimum
Input low voltage (V_{IL})	0.8 V dc maximum
Case operating temperature range (T_C)	-55°C to +125°C

1/ Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-HDBK-103.

2/ Must withstand the added P_D due to short circuit test (e.g., I_{OS}).

3/ Maximum junction temperature may be increased to +175°C during burn-in and steady-state life.

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at http://assist.daps.dla.mil/quicksearch/ or http://assist.daps.dla.mil or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 2.

3.2.3 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.

3.2.4 Die overcoat. Polyimide and silicone coatings are allowable as an overcoat on the die for alpha particle protection only. Each coated microcircuit inspection lot (see inspection lot as defined in MIL-PRF-38535) shall be subjected to and pass the internal moisture content test at 5000 ppm (see method 1018 of MIL-STD-883). The frequency of the internal water vapor testing shall not be decreased unless approved by the preparing activity for class M. The TRB will ascertain the requirements as provided by MIL-PRF-38535 for classes Q and V. Samples may be pulled any time after seal.

3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/ $-55°C \le T_A \le +125°C$ $4.5\ V \le V_{CC} \le 5.5\ V$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Output high voltage	V_{OH}	V_{CC} = 4.5 V, I_{OH} = -2.0 mA $V_{IN} = V_{IH}, V_{IL}$	1, 2, 3	All	2.4		V
Output low voltage	V_{OL}	V_{CC} = 4.5 V, I_{OH} = 8.0 mA $V_{IN} = V_{IH}, V_{IL}$	1, 2, 3	All		0.4	V
Input high voltage	V_{IH} 2/		1, 2, 3	All	2.2		V
Input low voltage	V_{IL} 2/		1, 2, 3	All		0.8	V
Input leakage current	I_{IX}	V_{IN} = 5.5 V to GND	1, 2, 3	All	-10	+10	µA
Output leakage current	I_{OZ}	V_{CC} = 5.5 V, V_{OUT} = 5.5 V to GND	1, 2, 3	All	-10	+10	µA
Operating supply current	I_{CC1}	V_{CC} = 5.5 V, I_{OUT} = 0 mA $f = 1/t_{RC}$ $\overline{W}$, $\overline{R}$, D_0 - D_8 pins are toggling between 0 V and 3 V $\overline{FF}$, $\overline{XO}$ / $\overline{HF}$ = 0 mA Q_0 - Q_8 = 0 mA $\overline{MR}$, $\overline{FL}$ / $\overline{RT}$ = 3.0 V	1, 2, 3	01, 02		115	mA
				03		130	
				04, 05		140	
				06		147	
Standby current	I_{CC2}	V_{CC} = 5.5 V, I_{OUT} = 0 mA All inputs = V_{IH} $\overline{FF}$, $\overline{XO}$ / $\overline{HF}$ = 0 mA Q_0 - Q_8 = 0 mA	1, 2, 3	All		30	mA
Power down current	I_{CC3}	V_{CC} = 5.5 V, I_{OUT} = 0 mA All inputs = V_{CC} -0.2 V $\overline{FF}$, $\overline{XO}$ / $\overline{HF}$ = 0 mA Q_0 - Q_8 = 0 mA	1, 2, 3	All		25	mA
Input capacitance	C_{IN} 3/	V_{CC} = 5.0 V T_A = +25°C, f = 1 MHz See 4.3.1c	4	All		8	pF
Output capacitance	C_{OUT} 3/	V_{CC} = 5.0 V T_A = +25°C, f = 1 MHz See 4.3.1c	4	All		8	pF
Functional tests		See 4.3.1d	7,8	All			

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C \le T_A \le +125°C$ $4.5\ V \le V_{CC} \le 5.5\ V$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Read cycle time	t_{RC}	See figure 3	9, 10, 11	01	100		ns
				02	80		
				03	65		
				04	50		
				05	40		
				06	35		
Access time	t_A		9, 10, 11	01		80	ns
				02		65	
				03		50	
				04		40	
				05		30	
				06		25	
Read recovery time	t_{RR}		9, 10, 11	01	20		ns
				02, 03	15		
				04,05,06	10		
Read pulse width	t_{PR}		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		
Read low to low Z	t_{LZR} 3/ 4/		9, 10, 11	All	3		ns
Read high to data valid	t_{DVR}		9, 10, 11	All	3		ns
Read high to high Z	t_{HZR} 3/ 4/		9, 10, 11	01,02,03		30	ns
				04		25	
				05		20	
				06		18	
Write cycle time	t_{WC}		9, 10, 11	01	100		ns
				02	80		
				03	65		
				04	50		
				05	40		
				06	35		
Write pulse width	t_{PW}		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C \le T_A \le +125°C$ $4.5\ V \le V_{CC} \le 5.5\ V$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Write high to low Z	t_{HWZ} 3/ 4/	See figure 3	9, 10, 11	All	10		ns
Write recovery time	t_{WR}		9, 10, 11	01	20		ns
				02, 03	15		
				04,05,06	10		
Data setup time	t_{SD}		9, 10, 11	01	40		ns
				02,03	30		
				04	20		
				05	18		
				06	15		
Data hold time	t_{HD}		9, 10, 11	01,02	10		ns
				03	5		
				04,05,06	0		
Master reset cycle time	t_{MRSC}		9, 10, 11	01	100		ns
				02	80		
				03	65		
				04	50		
				05	40		
				06	35		
Master reset pulse width	t_{PMR}		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		
Master reset recovery time	t_{RMR}		9, 10, 11	01	20		ns
				02,03	15		
				04,05,06	10		
Read high to master reset high	t_{RPW} 3/		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		
Write high to master reset high	t_{WPW} 3/		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C \le T_A \le +125°C$ $4.5\ V \le V_{CC} \le 5.5\ V$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Retransmit cycle time	t_{RTC}	See figure 3	9, 10, 11	01	100		ns
				02	80		
				03	65		
				04	50		
				05	40		
				06	35		
Retransmit pulse width	t_{PRT}		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		
Retransmit recovery time	t_{RTR}		9, 10, 11	01	20		ns
				02,03	15		
				04,05,06	10		
Master reset to empty flag low	t_{EFL}		9, 10, 11	01		100	ns
				02		80	
				03		65	
				04		50	
				05		40	
				06		35	
Master reset to half-full flag high	t_{HFH}		9, 10, 11	01		100	ns
				02		80	
				03		65	
				04		50	
				05		40	
				06		35	
Master reset to full flag high	t_{FFH}		9, 10, 11	01		100	ns
				02		80	
				03		65	
				04		50	
				05		40	
				06		35	
Read low to empty flag low	t_{REF}		9, 10, 11	01,02		60	ns
				03		45	
				04		35	
				05		30	
				06		25	
Read high to full flag high	t_{RFF}		9, 10, 11	01,02		60	ns
				03		45	
				04		35	
				05		30	
				06		25	

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C \le T_A \le +125°C$ $4.5\ V \le V_{CC} \le 5.5\ V$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Write high to empty flag high	t_{WEF}	See figure 3	9, 10, 11	01,02		60	ns
				03		45	
				04		35	
				05		30	
				06		25	
Write low to full flag low	t_{WFF}		9, 10, 11	01,02		60	ns
				03		45	
				04		35	
				05		30	
				06		25	
Write low to half-full flag low	t_{WHF}		9, 10, 11	01		100	ns
				02		80	
				03		65	
				04		50	
				05		40	
				06		35	
Read high to half-full flag high	t_{RHF}		9, 10, 11	01		100	ns
				02		80	
				03		65	
				04		50	
				05		40	
				06		35	
Effective read from write high	t_{RAE} 3/		9, 10, 11	01,02		60	ns
				03		45	
				04		35	
				05		30	
				06		25	
Effective read pulse width after empty flag high	t_{RPE}		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		
Effective write from read high	t_{WAF} 3/		9, 10, 11	01,02		60	ns
				03		45	
				04		35	
				05		30	
				06		25	
Effective write pulse width after full flag high	t_{WPF}		9, 10, 11	01	80		ns
				02	65		
				03	50		
				04	40		
				05	30		
				06	25		

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C \le T_A \le +125°C$ $4.5\ V \le V_{CC} \le 5.5\ V$ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Expansion out low delay from clock	t_{XOL}	See figure 3	9, 10, 11	01		80	ns
				02		65	
				03		50	
				04		40	
				05		30	
				06		25	
Expansion out high delay from clock	t_{XOH}		9, 10, 11	01		80	ns
				02		65	
				03		50	
				04		40	
				05		30	
				06		25	

1/ AC tests are performed with input rise and fall times of 5ns or less, timing reference levels of 1.5 V, input pulse levels of 0 V to 3.0 V, and the output load on figure 4.

2/ These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.

3/ Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table1.

4/ Transition is measured at steady-state high level -500 mV or steady-state low level +500 mV on the output from the 1.5 V level on the input.

3.5 Marking. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.

3.5.1 Certification/compliance mark. A compliance indicator “C” shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator “C” shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.

3.9 Verification and review. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

Device types	All	
Case outlines	U, X, Y	Z
Terminal number	Terminal symbol	
1	$\overline{W}$	NC
2	D_8	$\overline{W}$
3	D_3	D_8
4	D_2	D_3
5	D_1	D_2
6	D_0	D_1
7	$\overline{XI}$	D_0
8	$\overline{FF}$	$\overline{XI}$
9	Q_0	$\overline{FF}$
10	Q_1	Q_0
11	Q_2	Q_1
12	Q_3	NC
13	Q_8	Q_2
14	GND	Q_3
15	$\overline{R}$	Q_8
16	Q_4	GND
17	Q_5	NC
18	Q_6	$\overline{R}$
19	Q_7	Q_4
20	$\overline{XO}$ / $\overline{HF}$	Q_5
21	$\overline{EF}$	Q_6
22	$\overline{MR}$	Q_7
23	$\overline{FL}$ / $\overline{RT}$	$\overline{XO}$ / $\overline{HF}$
24	D_7	$\overline{EF}$
25	D_6	$\overline{MR}$
26	D_5	$\overline{FL}$ / $\overline{RT}$
27	D_4	NC
28	V_{CC}	D_7
29	-	D_6
30	-	D_5
31	-	D_4
32	-	V_{CC}

FIGURE 1. Terminal connections.

Reset and retransmit
Single device configuration/width expansion mode

Mode	Inputs			Internal status		Outputs		
	$\overline{MR}$	$\overline{RT}$	$\overline{XI}$	Read pointer	Write pointer	$\overline{EF}$	$\overline{FF}$	$\overline{HF}$
Reset	0	X	0	Location zero	Location zero	0	1	1
Retransmit	1	0	0	Location zero	Unchanged	X	X	X
Read/Write	1	1	0	Increment 1/	Increment 1/	X	X	X

1/ Pointer will increment if flag is high.

Reset and first load truth table
Depth expansion/compound expansion mode

Mode	Inputs			Internal status		Outputs	
	$\overline{MR}$	$\overline{FL}$	$\overline{XI}$	Read pointer	Write pointer	$\overline{EF}$	$\overline{FF}$
Reset first device	0	0	1/	Location zero	Location zero	0	1
Reset all other devices	0	1	1/	Location zero	Location zero	0	1
Read/Write	1	X	1/	X	X	X	X

1/ $\overline{XI}$ is connected to $\overline{XO}$ of previous device.

NOTE: $\overline{MR}$ = Reset input, $\overline{FL}$ / $\overline{RT}$ = First load/retransmit $\overline{EF}$ = Empty flag output, $\overline{FF}$ = Full flag output, $\overline{XI}$ = Expansion input, and $\overline{HF}$ = Half-full flag output

FIGURE 2. Truth table.

ASYNCHRONOUS READ AND WRITE TIMING DIAGRAM

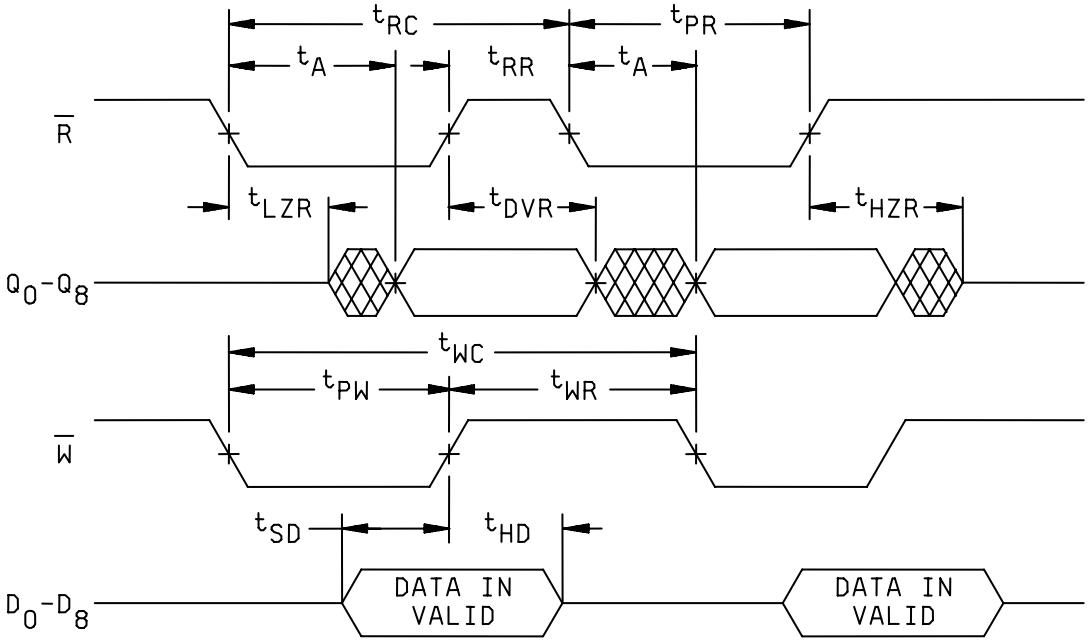
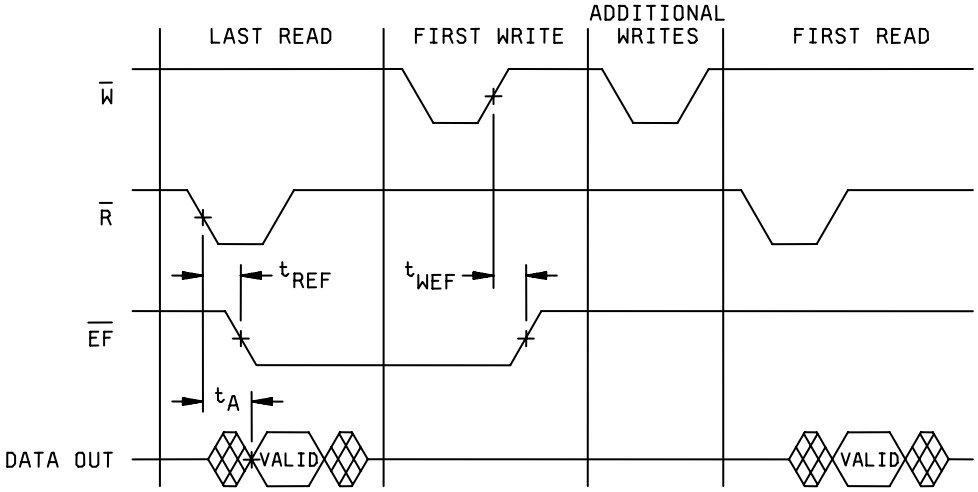
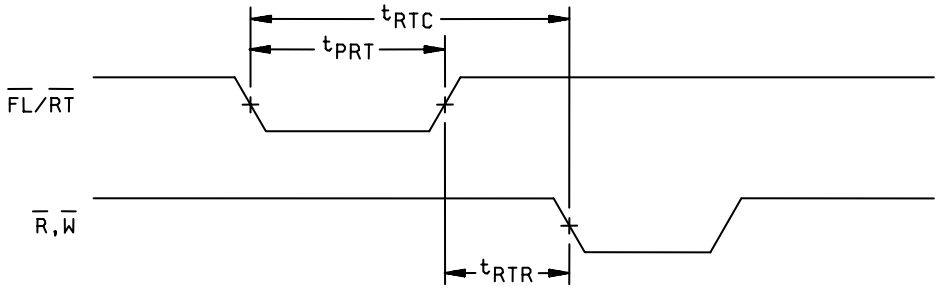


FIGURE 3. Timing waveforms.

LAST READ TO FIRST WRITE EMPTY FLAG TIMING DIAGRAM



RETRANSMIT TIMING DIAGRAM

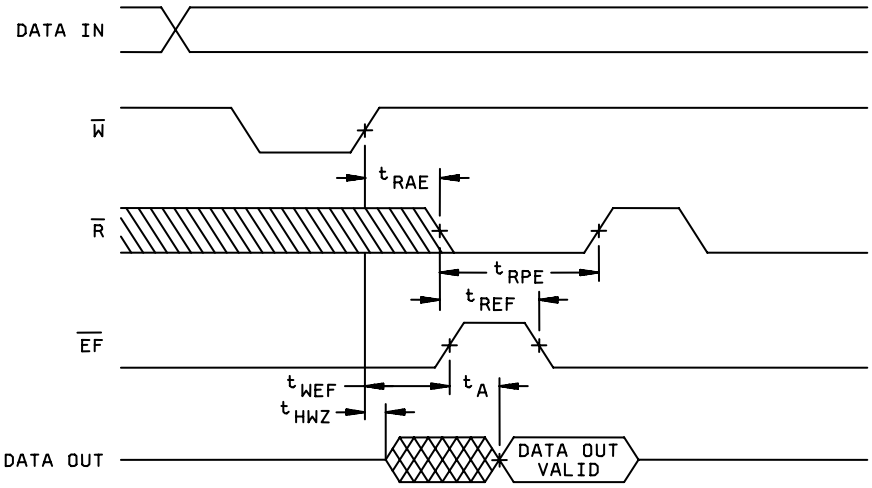


NOTES:

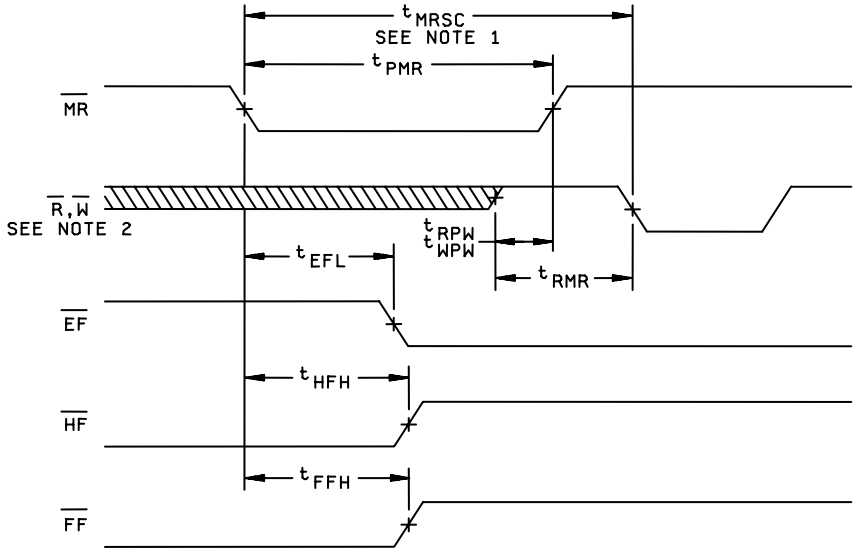
1. $t_{RTC} = t_{PRT} + t_{RTR}$.
2. EF, HF, and FF may change state during retransmit as a result of the offset of the read write pointer, but flags will be valid at t_{RTC}.

FIGURE 3. Timing waveforms - Continued.

EMPTY FLAG AND READ BUBBLE-THROUGH MODE TIMING DIAGRAM



MASTER RESET TIMING DIAGRAM

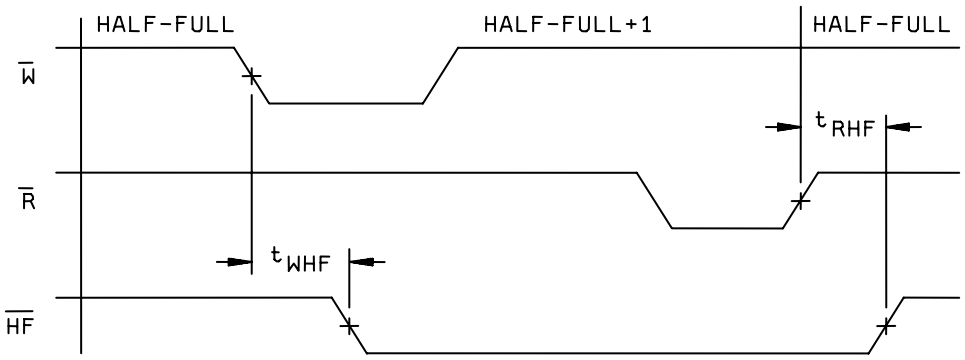


NOTES:

1. $t_{MRSC} = t_{PMR} + t_{RMR}$.
2. $\overline{W}$ and $\overline{R}$ = V_{IH} around the rising edge of $\overline{MR}$

FIGURE 3. Timing waveforms - Continued.

HALF-FULL FLAG TIMING DIAGRAM



LAST WRITE READ FULL FLAG TIMING DIAGRAM

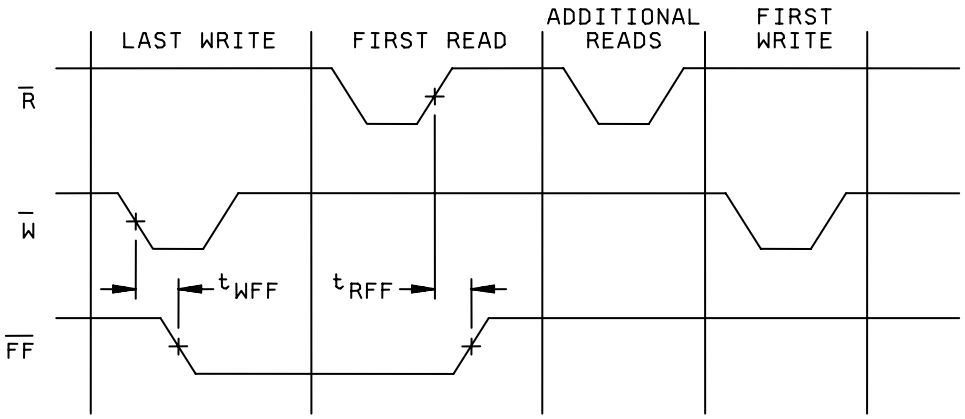


FIGURE 3. Timing waveforms - Continued.

FULL FLAG AND WRITE BUBBLE-THROUGH MODE TIMING DIAGRAM

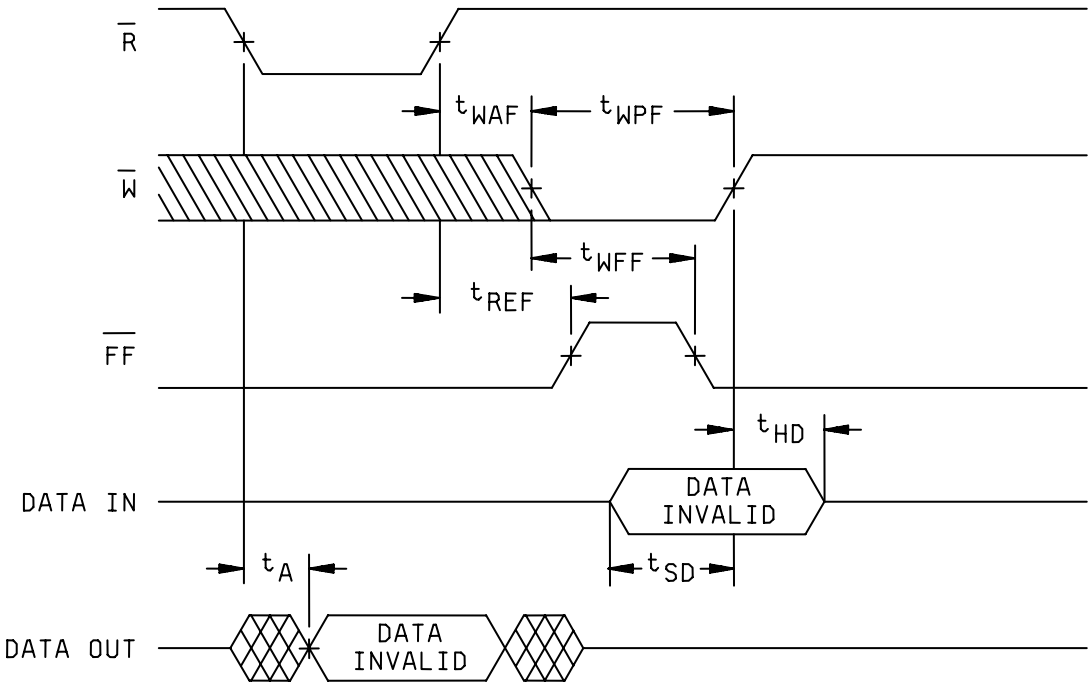
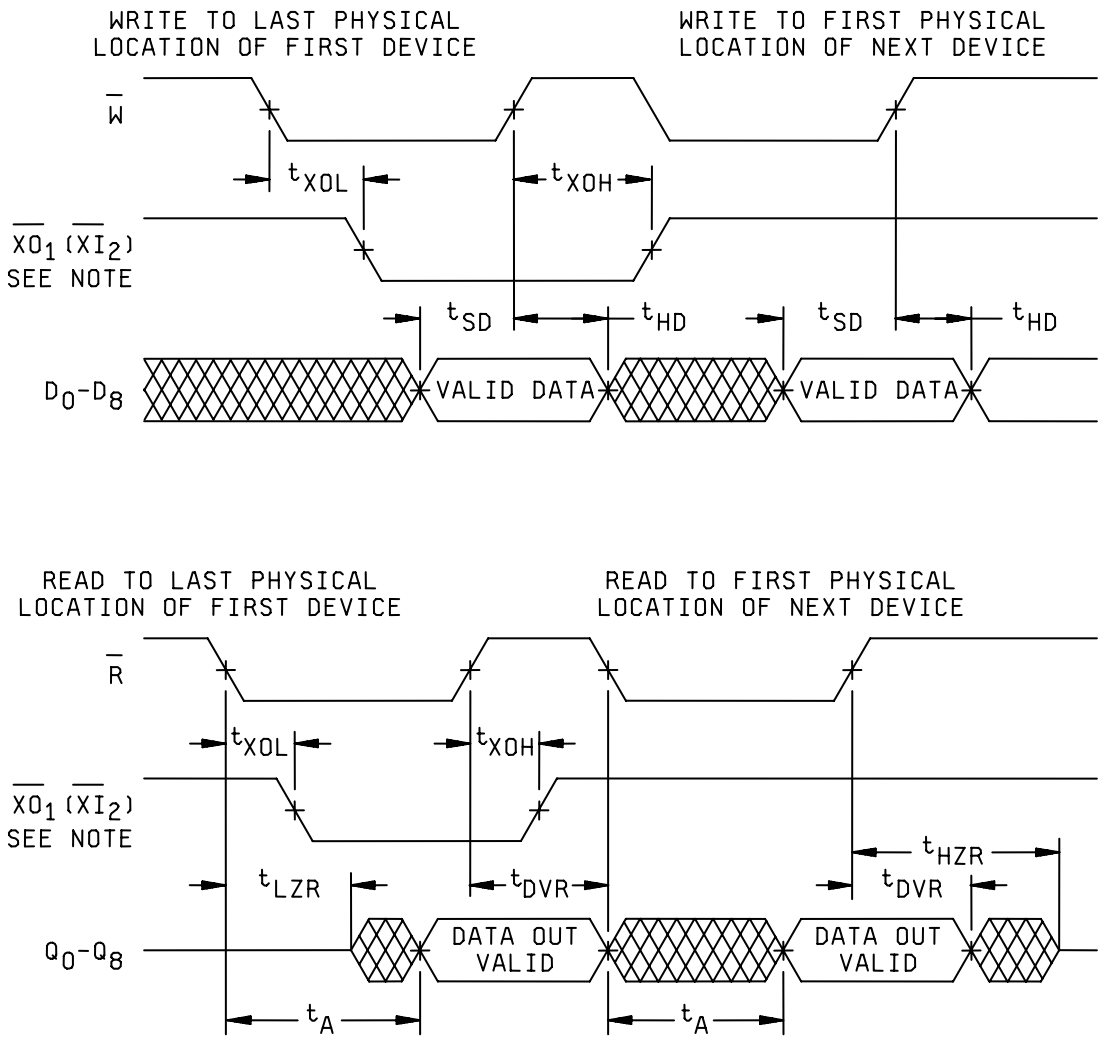


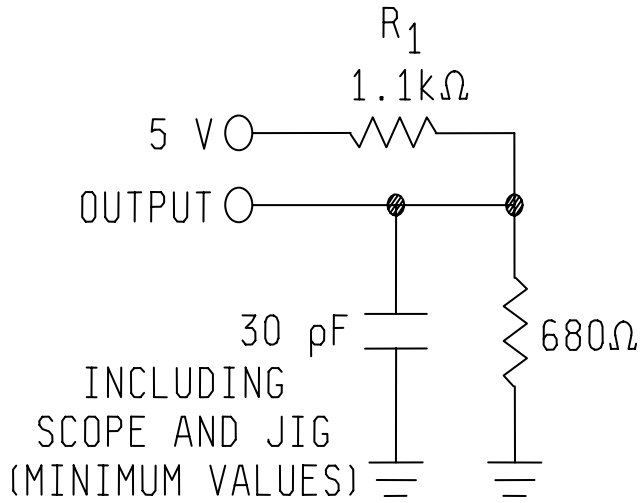
FIGURE 3. Timing waveforms - Continued.

EXPANSION TIMING DIAGRAM



NOTE: Expansion Out of device 1 ($\overline{XO}_1$) is connected to Expansion In of device 2 ($\overline{XI}_2$).

FIGURE 3. Timing waveforms - Continued.



CIRCUIT A
OUTPUT LOAD

AC test conditions

Input pulse levels	GND to 3.0 V
Input rise and fall times	5 ns
Input timing reference levels	1.5 V
Output reference levels	1,5 V

FIGURE 4. Output load circuit and test conditions.

4. VERIFICATION

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.

(2) T_A = +125°C, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroup 4 (C_{IN} and C_{OUT} measurement) shall be measured only for the initial test and after process or design changes which may affect capacitance. Sample size is fifteen devices with no failures and all input and output terminals tested.

d. Subgroups 7 and 8 tests shall include verification of the truth table.

4.3.2 Groups C and D inspections.

a. End-point electrical parameters shall be as specified in table II herein.

b. Steady-state life test conditions, method 1005 of MIL-STD-883.

(1) Test condition D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.

(2) TA = +125°C, minimum.

(3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements. 1/ 2/ 3/

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	---
Final electrical test parameters (method 5004)	1*, 2, 3, 7*, 8A, 8B, 9, 10,11
Group A test requirements (method 5005)	1, 2, 3, 4**, 7, 8A, 8B, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	2, 3, 7, 8A, 8B

1/ * indicates PDA applies to subgroups 1 and 7.

2/ ** see 4.3.1c.

3/ see 4.3.1d.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 Record of users. Military and industrial users shall inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.5 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 06-11-08

Approved sources of supply for SMD 5962-89863 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN 1/	Vendor CAGE number	Vendor similar PIN 2/
5962-8986301UA	0C7V7 3/	CY7C421-80KMB IDT7201SA80XEB
5962-8986301XA	0C7V7 3/	CY7C420-80DMB IDT7201SA80DB
5962-8986301YA	0C7V7 3/ 3/	CY7C421-80DMB IDT7201SA80TDB MM1P-67201-55MB
5962-8986301ZA	0C7V7 3/ 3/	CY7C421-80LMB IDT7201SA80LB MM4J-67201-55MB
5962-8986302UA	0C7V7 3/	CY7C421-65KMB IDT7201SA65XEB
5962-8986302XA	0C7V7 3/	CY7C420-65DMB IDT7201SA65DB
5962-8986302YA	0C7V7 3/ 3/	CY7C421-65DMB IDT7201SA65TDB MM1P-67201-55MB
5962-8986302ZA	0C7V7 3/ 3/	CY7C421-65LMB IDT7201SA65LB MM4J-67201-55MB
5962-8986303UA	0C7V7 3/	CY7C421-50KMB IDT7201SA50XEB
5962-8986303XA	0C7V7 3/	CY7C420-50DMB IDT7201SA50DB
5962-8986303YA	0C7V7 61772 3/	CY7C421-50DMB IDT7201SA50TDB MM1P-67201-45MB
5962-8986303ZA	0C7V7 3/ 3/	CY7C421-50LMB IDT7201SA50LB MM4J-67201-45MB
5962-8986304UA	0C7V7 3/	CY7C421-40KMB IDT7201SA40XEB
5962-8986304XA	0C7V7 3/	CY7C421-40DMB IDT7201SA40DB

See footnotes at end of table.

Standard microcircuit drawing PIN 1/	Vendor CAGE number	Vendor similar PIN 1/
5962-8986304YA	0C7V7 3/ 3/	CY7C421-40DMB IDT7201SA40TDB MM1P-67201-35MB
5962-8986304ZA	0C7V7 3/ 3/	CY7C421-40LMB IDT7201SA40LB MM4J-67201-35MB
5962-8986305UA	0C7V7 3/	CY7C421-30KMB IDT7201SA30XEB
5962-8986305XA	0C7V7 3/	CY7C420-30DMB IDT7201SA30DB
5962-8986305YA	0C7V7 61772	CY7C421-30DMB IDT7201SA30TDB
5962-8986305ZA	0C7V7 3/	CY7C421-30LMB IDT7201SA30LB
5962-8986306UA	0C7V7	CY7C421-25KMB
5962-8986306XA	0C7V7	CY7C420-25DMB
5962-8986306YA	0C7V7	CY7C421-25DMB
5962-8986306ZA	0C7V7	CY7C421-25LMB

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed, contact the Vendor to determine its availability.

2/ Caution: Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

3/ Not available from an approved source.

Vendor CAGE number	Vendor name and address
0C7V7	QP Semiconductor 2945 Oakmead Village Court Santa Clara, CA 95051
61772	Integrated Device Technology, Inc. 2975 Stender Way Santa Clara, CA 95054

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